

Variable capacitance diode for AM tuning

AMチューナ用電圧可変容量ダイオード

KV1560, KV1560NT, KV1562M, KV1563M, KV1563BM

FEATURES

- Excellent Matching Between Elements
- Excellent Linearity of The CV Curve
- High Q: Q=200 to
- Extra Large Capacitance Ratio: A=17.0 to
- 優れた素子間マッチング
- CV特性の優れた直線性
- 高いQ値: Q=200~
- 極めて大きな容量変化比: A=17.0~

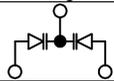
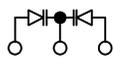
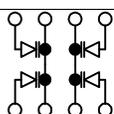
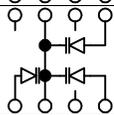
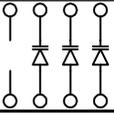
CLASSIFICATION

Rank		1	2	3	4
		C	MIN	428	446
C ₁	MAX	452	470	488	506

ORDERING INFORMATION

- KV1560NT
 - KV1560TL...Storage direction: TL(Left type)
 - KV1562MTL...Storage direction: TL(Left type)
 - KV1563MTL...Storage direction: TL(Left type)
 - KV1563BMTL...Storage direction: TL(Left type)
- * Part name + Storage direction

PACKAGE OUTLINE

Part name	Package	Marking	Pin configuration
KV1560	 SOT23L-3	A6	
KV1560NT	 TO92-3	560	
KV1562M	 SOP-8	562	
KV1563M	 SOP-8	563	
KV1563BM	 SOP-8	63B	

ELECTRICAL CHARACTERISTICS

T_A=25°C

Parameter 項目	Symbol 記号	Value 規格			Units 単位	Conditions 条件
		MIN	TYP	MAX		
Reverse Voltage 逆方向電圧	V _R	16			V	I _R =10μA
Reverse Current 逆方向電流	I _R			100	nA	V _R =10V
Diode Capacitance 容量値	C ₁	428.0		506.0	pF	V _R =1V, f=1MHz
	C _{4.5}		100		pF	V _R =4.5V, f=1MHz
	C ₈	20.0		27.5	pF	V _R =8V, f=1MHz
Capacitance Tolerance 容量偏差	ΔC ₁			1.0	%	KV1560, KV1560NT V _R =1V, f=1MHz*1
				1.2		
				1.1		
				2		
	ΔC _{4.5}			2.0	%	KV1560, KV1560NT KV1562M KV1563M KV1563BM V _R =4.5V, f=1MHz*1
				2.2		
				2.1		
				3		
	ΔC ₈			2.0	%	KV1560, KV1560NT KV1562M KV1563M KV1563BM V _R =8V, f=1MHz*1
				2.2		
				2.1		
				3		
Q	Q	200				V _R =1V, f=1MHz
Capacitance Ratio 容量変化比	A	17.0				C ₁ /C ₈

* Diode Capacitance measured with Agilent 4279A or equivalent instruments (at OSC level 20±5mVrms)
容量測定器は、Agilent 4279A又は相当品。OSCレベル 20±5mVrms。

*1 (C_{MAX}-C_{MIN})/C_{MIN}×100

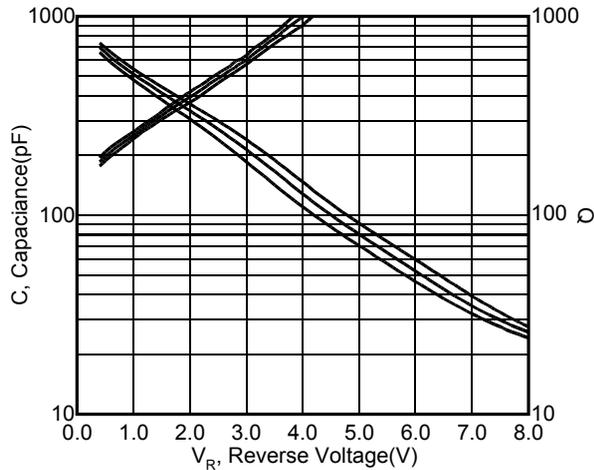
ABSOLUTE MAXIMUM RATINGS

Parameter	項目	Symbol 記号	Rating 定格	Unit 単位	Remarks 備考
Reverse Voltage	逆方向電圧	V_R	20	V	KV1560, KV1560NT KV1562M, KV1563M, KV1563BM
			16		
Forward Current	順方向電流	I_F	50	mA	
Power Dissipation	許容消費電力	P_D	100	mW	
Storage Temperature Range	保存温度範囲	T_{STG}	-55 to 150	°C	
Operating Temperature Range	動作温度範囲	T_{OP}	-55 to +85	°C	

TYPICAL PREFORMNCE CHARACTERISTICS

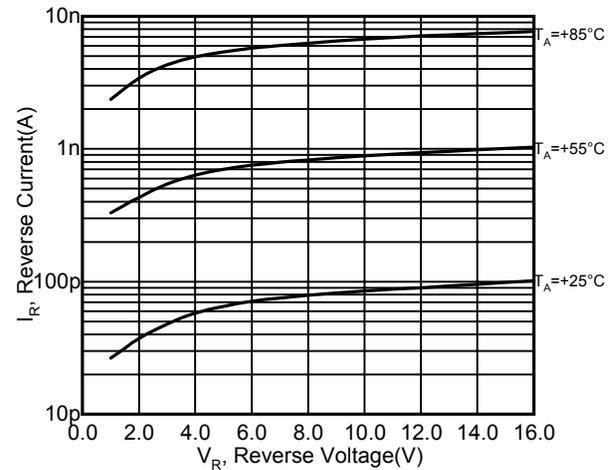
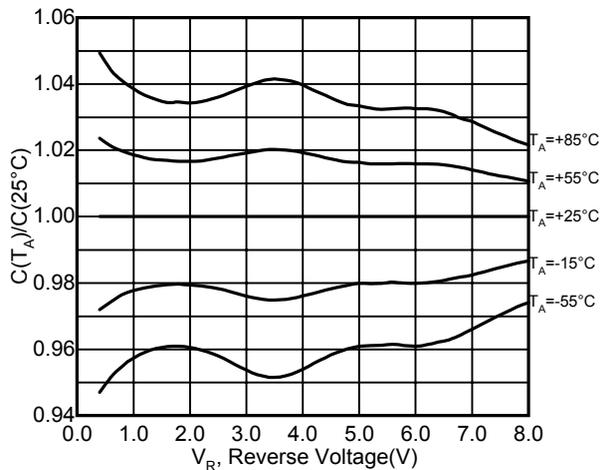
■ Capacitance, Q versus Reverse Voltage

逆方向電圧対容量、Q

f=1MHz, $T_A=25^\circ\text{C}$ 

■ Reverse Current versus Reverse Voltage

逆方向電圧対逆電流

 $T_A=+25 / +55 / +85^\circ\text{C}$ ■ $C(T_A)/C(25^\circ\text{C})$ versus Reverse Voltage逆方向電圧対 $C(T_A)/C(25^\circ\text{C})$ f=1MHz $T_A=-55$ to $+85^\circ\text{C}$ 

■ Capacitance Temperature Coefficient versus Reverse Voltage

逆方向電圧対温度係数

f=1MHz, $T_A=25^\circ\text{C}$ 